

VSKJS209/150P

Vishay High Power Products

Schottky Rectifier, 200 A



ADD-A-PAK

PRODUCT SUMMARY				
I _{F(AV)}	200 A			

MECHANICAL DESCRIPTION

The Generation 5 of ADD-A-PAK module combine the excellent thermal performance obtained by the usage of direct bonded copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device.

The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread.

The Generation 5 of ADD-A-PAK module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · UL pending
- · Totally lead (Pb)-free, RoHS compliant
- Designed and qualified for industrial level

DESCRIPTION

The VSKJS209.. Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	A . O		
V _{RRM}		150	V		
I _{FSM}	t _p = 5 μs sine	11 300	А		
V _F	100 Apk, T _J = 125 °C	0.76	V		
TJ	Range	- 55 to 175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VSKJS209/150P	UNITS		
Maximum DC reverse voltage	V _R	150	V		
Maximum working peak reverse voltage	V_{RWM}	130	V		

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per module		50 % duty cycle at T _C = 107 °C, rectangular waveform		200	
forward current	per leg	I _{F(AV)}			100	
Maximum peak one cycle		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	11 300	Α
non-repetitive surge current			10 ms sine or 6 ms rect. pulse		1600	
Non-repetitive avalanche ener	repetitive avalanche energy E _{AS}		$T_J = 25$ °C, $I_{AS} = 1.8$ Amps, $L = 10$ mH		15	mJ
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1	Α

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		100 A	T _J = 25 °C	0.96	V
Maximum forward valtage drep	V (1)	200 A		1.21	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	100 A	T _J = 125 °C	0.76	
		200 A		0.96	
Maximum reverse leakage current	. (1)	T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C		85	IIIA
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		3000	pF
Typical series inductance	L _S	From top of terminal hole to mounting plane		7.0	nΗ
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted (1 s) 3500		V	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	,	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.6	°C/W
Maximum thermal resistance, case to heatsink		R _{thCS} Mounting surface, smooth and grease		0.1	C/VV
Approximate weight				110	g
Approximate weight				4	OZ.
Mounting torque ± 10 %	to heatsink			5	Nm
	busbar			4	INIII
Case style			JEDEC	TO-2	40AA



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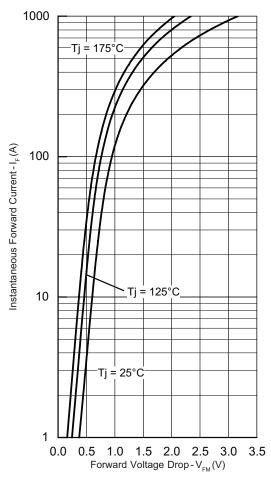


Fig. 1 - Maximum Forward Voltage Drop Characteristics

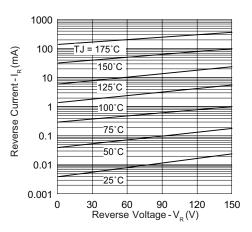


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

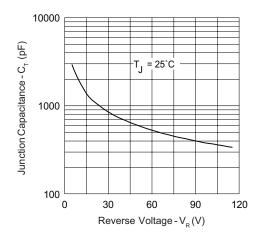


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

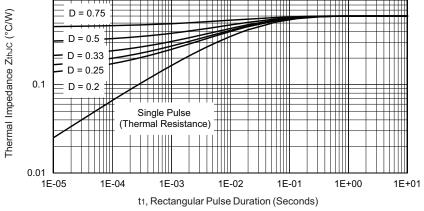


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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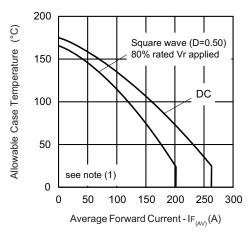


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

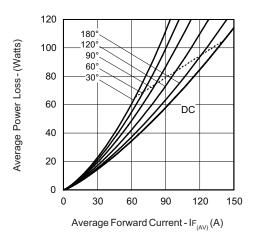


Fig. 6 - Forward Power Loss Characteristics

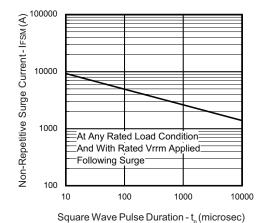


Fig. 7 - Maximum Non-Repetitive Surge Current

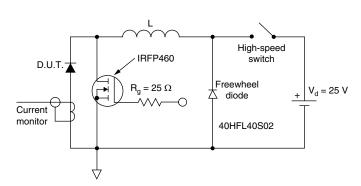


Fig. 8 - Unclamped Inductive Test Circuit

Note

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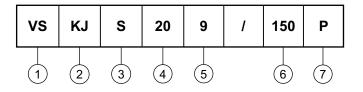
 $\begin{array}{l} \mbox{(1)} \ \ \mbox{Formula used:} \ T_{C} = T_{J} \mbox{-} (\mbox{Pd} + \mbox{Pd}_{REV}) \ x \ R_{thJC}; \\ \mbox{Pd} = \mbox{Forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (\mbox{see fig. 6}); \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = V_{R1} \ x \ I_{R} \ (1 \mbox{-} D); \ I_{R} \ at \ V_{R1} = 80 \ \% \ rated \ V_{R} \\ \end{array}$



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ORDERING INFORMATION TABLE

Device code



1 - Vishay HPP

2 - Circuit configuration:

KJ = ADD-A-PAK - 2 diodes/common anode

3 - S = Schottky diode

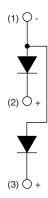
4 - Average rating (x 10)

5 - Product silicon identification

6 - Voltage rating (150 = 150 V)

7 - Lead (Pb)-free

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
	Dimensions	http://www.vishay.com/doc?95174			



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